


Transport in the two-dimensional Fermi-Hubbard model: Lessons from weak couplingThomas G. Kiely^{✉*} and Erich J. Mueller^{✉†}*Laboratory of Atomic and Solid State Physics, Cornell University, Ithaca, New York 14853, USA* (Received 8 June 2021; revised 5 October 2021; accepted 5 October 2021; published 25 October 2021)

We use quantum kinetic theory to calculate the thermoelectric transport properties of the two-dimensional single-band Fermi-Hubbard model in the weak coupling limit. For generic filling, we find that the high-temperature limiting behaviors of the electrical ($\sim T$) and thermal ($\sim T^2$) resistivities persist down to temperatures of order the hopping matrix element $T \sim t$, almost an order of magnitude below the bandwidth. At half filling, perfect nesting leads to anomalous low-temperature scattering and nearly T -linear electrical resistivity at all temperatures. We hypothesize that the T -linear resistivity observed in recent cold atom experiments is continuously connected to this weak coupling physics and suggest avenues for experimental verification. We find a number of other novel thermoelectric results, such as a low-temperature Wiedemann-Franz law with Lorenz coefficient $5\pi^2/36$.

DOI: [10.1103/PhysRevB.104.165143](https://doi.org/10.1103/PhysRevB.104.165143)**I. INTRODUCTION**

One of the most significant open problems in condensed matter physics is the origin of “strange metal” behavior in strongly correlated materials. This non-Fermi-liquid behavior is often identified experimentally through anomalous transport properties: a DC resistivity which is T -linear down to low temperatures and a mean-free path which becomes shorter than the lattice spacing at high temperatures. The latter is referred to as a violation of the the Mott-Ioffe-Regel (MIR) limit. These observations differ from expected Fermi liquid behavior, which is characterized by a resistivity that is proportional to T^2 at low temperatures and a saturation of the MIR bound at high temperatures [1–3]. Such anomalous behaviors have been observed in a diverse array of strongly correlated materials [4–9] and have invited a variety of sophisticated theoretical and numerical approaches to explain them [10–18].

One longstanding difficulty of studying these materials directly is the complex interplay of interactions between electrons, phonons, and impurities. For this reason, there has been considerable interest in the cold atom community to simulate nontrivial strongly correlated model systems. The Fermi-Hubbard model is a natural starting point for these investigations, as cold atoms in an optical lattice naturally realize a nearest-neighbor hopping model with onsite interactions. The first is controlled using the lattice depth, while the second is tuned via a Feshbach resonance [19,20]. Optical lattices are, furthermore, defect-free and do not support phonons. This puts us in a novel transport regime: current dissipation arises only from the analog of electron-electron scattering. At low temperatures, the dominant processes involve umklapp scattering, where the lattice absorbs momentum corresponding to a reciprocal lattice vector [21].

Recent experimental evidence from the Bakr group indicates that the two-dimensional (2D) realization of this model

has a high-temperature strange metal phase [22]. This conclusion is supported by advanced numerical methods [15–18] and analytic high-temperature expansions [13]. Of particular note, the authors found that the Nernst-Einstein decomposition of the conductivity $\sigma = D\chi$ does not shed light onto the origin of this behavior: both the diffusion constant and the charge compressibility have nontrivial temperature dependencies in the strange metal regime, conspiring to give a T -linear resistivity. Furthermore, the diffusion constant appears to saturate a high-temperature bound that would be conceptually consistent with the MIR limit [22].

In this paper we clarify this story by studying weak-coupling transport in the 2D Fermi-Hubbard model. We use a quantum kinetic theory to show that, even at weak coupling, the resistivity is nearly T -linear down to temperatures an order of magnitude below the bandwidth. At temperatures that are large compared to the bandwidth, this behavior is attributed to a vanishing inverse effective mass, arising from competing contributions from both the top and bottom of the band. Despite the diverging resistivity, the quasiparticle scattering rate in this regime saturates at an interaction-dependent value that is well below the MIR bound. Remarkably, at intermediate temperatures, T -linearity arises from a nontrivial interplay between the effective mass and the scattering lifetime. This is analogous to the aforementioned “conspiracy” between the compressibility and diffusion constant seen in experiments. We demonstrate that T -linearity persists to arbitrarily low temperatures in the vicinity of half filling, where the density of states diverges and the Fermi surface is perfectly nested. Away from half filling we find the the conventional T^2 behavior at sufficiently low temperature, with a crossover to T -linearity at higher temperature. The crossover temperature vanishes at half filling and for small Fermi surfaces $|\mu_F| > 2t$, where umklapp scattering is forbidden.

The T -linear resistivity of the half-filled 2D Fermi-Hubbard model has been the subject of previous theoretical studies [23–26], and similar behavior was observed in other models with van Hove singularities, such as twisted bilayer

*tgk37@cornell.edu

†em256@cornell.edu

graphene [27]. These references draw interesting connections to marginal Fermi liquid theory [10]. Our paper uses elementary arguments to show that this feature can be found at weak coupling and explains the behavior in terms of kinetic theory and perfect nesting. Furthermore, we model how thermal population of the nested Fermi surface affects transport away from half filling. This is particularly important because nesting-driven instabilities at half filling will always lead to a Mott transition at sufficiently low temperatures in two dimensions [28,29].

Beyond calculating the conductivity σ , we explore thermal conductivity κ and more general thermoelectric properties. At low temperatures we find that the Lorenz number $L = \kappa/(\sigma T)$ approaches a constant. This Wiedemann-Franz law [30] is expected when the same degrees of freedom are responsible for thermal and electrical transport. Our Lorenz number, however, differs from what is found in a system where the dissipation is dominated by impurity scattering. The Wiedemann-Franz law breaks down at high temperature.

We organize our paper as follows. In Sec. II we discuss the 2D Fermi-Hubbard model as well as the variational approach that we use to solve the Boltzmann equation [31]. In Sec. III we present our results, divided between the electrical properties (Sec. III A) and the full thermoelectric matrix (Sec. III B). We discuss the theoretical context and experimental implications of our work in Sec. IV, and in Sec. V we summarize our conclusions.

II. MODEL

In this paper we study the 2D single-band Fermi-Hubbard model on a rectangular lattice with nearest-neighbor hopping

$$\mathcal{H} = -t \sum_{\langle ij \rangle, \sigma} (c_{i\sigma}^\dagger c_{j\sigma} + \text{H.c.}) + U \sum_i c_{i\uparrow}^\dagger c_{i\downarrow}^\dagger c_{i\downarrow} c_{i\uparrow}, \quad (1)$$

where $c_{i\sigma}^\dagger$ is the fermionic annihilation (creation) operator on site i with spin σ . In condensed matter systems, this model describes highly localized orbitals with an onsite interaction parameterized by U . It is a natural model Hamiltonian for fermionic cold atoms in an optical lattice, where the interaction strength U is tuned using a Feshbach resonance and the tunneling strength t is set by the optical lattice depth.

Although we are largely thinking of cold atom realizations, we use the language of electronic systems. We interpret a force \mathbf{F} in terms of an electric field $\mathbf{E} = \mathbf{F}/e$. The charge current is simply the number current times the electron charge $\mathbf{j} = e\mathbf{j}_n$.

A. Linearized Boltzmann equation

The richness of the Hubbard model arises from the non-commutativity of the kinetic and interaction terms: the kinetic term is diagonal in momentum space, with a dispersion $\epsilon_k = -2t \cos(k_x) - 2t \cos(k_y)$, while the interaction term is diag-

onal in real space. Our paper will study this model in the weak-coupling regime $U \ll t$, such that the interaction may be treated as a perturbation. In this limit the excitations are quasiparticle states with well-defined crystal momenta. The interaction term introduces collisions between quasiparticles, giving them a finite lifetime. Fermi liquid theory holds that there is a domain of finite U/t within which this analysis is valid.

We model the fermion distribution function $f_k(r)$, which counts how many quasiparticles of a given spin state are at position r with momentum $\hbar k$. The particle density is $n(r) = 2 \int \frac{d^2k}{(2\pi)^2} f_k(r)$, where the factor of 2 accounts for spin. The distribution function obeys a Boltzmann equation

$$\partial_t f_k + \nabla_r f_k \cdot \mathbf{v}_k + e\mathbf{E} \cdot \nabla_k f_k = I_k[f], \quad (2)$$

where $\mathbf{v}_k = \frac{1}{\hbar} \nabla_k \epsilon_k$ is the velocity. The collision integral $I_k[f]$ is a functional that determines the rate at which particles scatter into and out of the momentum state k . It can be calculated with Fermi's Golden Rule:

$$I_k[f] = -\frac{2\pi}{\hbar} \sum_{if} p_i |\langle f | \mathcal{H}_{\text{int}} | i \rangle|^2 (n_k^{(f)} - n_k^{(i)}) \delta(\epsilon_f - \epsilon_i), \quad (3)$$

where $|i\rangle$ and $|f\rangle$ are Slater determinants, p_i is the probability of initially being in state $|i\rangle$, $\mathcal{H}_{\text{int}} = U \sum_i c_{i\uparrow}^\dagger c_{i\downarrow}^\dagger c_{i\downarrow} c_{i\uparrow}$, $n_k^{(i)} = \langle i | c_{k\sigma}^\dagger c_{k\sigma} | i \rangle$, and $f_k = \langle c_{k\sigma}^\dagger c_{k\sigma} \rangle = \sum_i p_i n_k^{(i)}$. Replacing \mathcal{H}_{int} with the full many-body T -matrix gives a formally exact value for the decay rate; Eq. (3) corresponds to the Born approximation, where one keeps only the leading-order term after expanding in powers of U/t .

If one assumes that the momentum states are uncorrelated, the collision integral is given by

$$I_k[f] = \frac{2\pi U^2}{\hbar} \sum_{k', k'', k''', Q} \delta_{k+k'-k''-k'''-Q} \delta(\epsilon_f - \epsilon_i) \times [f'' f''' (1-f)(1-f') - f f' (1-f'')(1-f''')], \quad (4)$$

where we used the short-hand notation $f = f_k$, $f' = f_{k'}$, and so on. We explicitly included the sum over reciprocal lattice vectors, Q , which accounts for momentum nonconserving umklapp scattering events. Note that the integrand is exactly zero for $f_k = f_k^0(r)$, the Fermi-Dirac distribution

$$f_k^0(r) = \frac{1}{e^{\beta(r)[\epsilon_k - \mu(r)]} + 1}. \quad (5)$$

We take $\beta(r) = 1/k_B T(r)$ and $\mu(r)$ to be slowly varying, treating $\nabla\beta$, $\nabla\mu$, and \mathbf{E} as small parameters.

We linearize the Boltzmann equation by taking $f_k - f_k^0 = -\Phi_k \frac{\partial f_k^0}{\partial \epsilon_k}$, where Φ_k is formally small. We can always choose β and μ so that this perturbation does not change the density or energy, $\int \frac{d^2k}{(2\pi)^2} \Phi_k \frac{\partial f_k^0}{\partial \epsilon_k} = \int \frac{d^2k}{(2\pi)^2} (\epsilon_k - \mu) \Phi_k \frac{\partial f_k^0}{\partial \epsilon_k} = 0$. The linearized collision integral, in the thermodynamic limit, is given by

$$I_k[\Phi] = -\frac{\Lambda\beta}{(2\pi)^3} \sum_Q \int d^2k' \int d^2k'' \int d^2k''' (\Phi_k + \Phi_{k'} - \Phi_{k''} - \Phi_{k'''}) f_k^0 f_{k'}^0 (1-f_k^0)(1-f_{k''}^0) \times \delta^2(k+k'-k''-k'''-Q) \delta(\epsilon_k + \epsilon_{k'} - \epsilon_{k''} - \epsilon_{k'''}), \quad (6)$$

where $\Lambda = \frac{U^2 a^4}{\hbar}$ and a is the lattice spacing.

B. Variational solution

The thermoelectric matrix is obtained from the steady-state solutions to the Boltzmann equation, where $\partial_t f_k = 0$. The resulting equation is an inhomogeneous integral equation for Φ_k . We follow the procedure set out in Ref. [31] to obtain a variational bound on the transport coefficients. We make the ansatz $\Phi_k = \sum_i \xi_i \phi_k^{(i)}$, where $\phi_k^{(i)}$ are a fixed set of trial functions. The goal will be to determine the optimal set of coefficients $\{\xi_i\}$, such that the resulting distribution is as close to the actual Boltzmann equation solution as possible. In our numerical calculations we will use a two-term ansatz, with $\phi_k^{(1)} = (\nabla_k \epsilon_k)_x$ and $\phi_k^{(2)} = (\epsilon_k - \mu)(\nabla_k \epsilon_k)_x$, though in this section we consider the completely general case. The theory becomes exact in the limit where the $\phi_k^{(i)}$ form a complete set.

We define the particle and heat currents arising from each trial function, respectively, as

$$\begin{aligned} j_\alpha^{(i)} &= -2e \int \frac{d^2k}{(2\pi)^2} (\nabla_k \epsilon_k)_\alpha \phi_k^{(i)} \frac{\partial f_k^0}{\partial \epsilon_k}, \\ u_\alpha^{(i)} &= -2 \int \frac{d^2k}{(2\pi)^2} (\epsilon_k - \mu) (\nabla_k \epsilon_k)_\alpha \phi_k^{(i)} \frac{\partial f_k^0}{\partial \epsilon_k}, \end{aligned} \quad (7)$$

where $\alpha = x, y, z$. These currents are generated by the electric field \mathbf{E} included explicitly in Eq. (2), as well as a spatially homogeneous temperature gradient $\nabla_r T$. The latter force comes from the spatial derivative of $\beta(r)$ in the second term of Eq. (2). Gradients of $\mu(r)$ play the same role as the electric field, and we follow the standard condensed matter convention of defining an effective field $E + (1/e)\nabla_r \mu$ that generates particle currents [32]. In what follows, we will use the variable E to denote this combination of an external field and the gradient of the chemical potential. Furthermore, we will neglect the effect of density gradients on the steady-state properties of the system. In this particular problem, neglecting density gradients can be justified by noting that the Hartree terms which couple density gradients to currents are of subleading order in U/t . Furthermore, we envision a current-carrying state of constant density.

Linearizing the Boltzmann equation, multiplying by Φ_k , and integrating over k yields

$$\sum_i \xi_i \left[\frac{j_\alpha^{(i)} E_\alpha}{T} + u_\alpha^{(i)} \nabla_\alpha \left(\frac{1}{T} \right) \right] = \frac{1}{T} \sum_{ij} \xi_i \xi_j P_{ij}, \quad (8)$$

where

$$\begin{aligned} P_{ij} &= \frac{\Lambda \beta}{(2\pi)^5} \sum_Q \int d^2k \int d^2k' \int d^2k'' \int d^2k''' (\phi_k^{(i)} + \phi_{k'}^{(i)} - \phi_{k''}^{(i)} - \phi_{k'''}^{(i)}) (\phi_k^{(j)} + \phi_{k'}^{(j)} - \phi_{k''}^{(j)} - \phi_{k'''}^{(j)}) \\ &\quad \times f_k^0 f_{k'}^0 (1 - f_{k''}^0) (1 - f_{k'''}^0) \delta(k + k' - k'' - k''' - Q) \delta(\epsilon_k + \epsilon_{k'} - \epsilon_{k''} - \epsilon_{k'''}). \end{aligned} \quad (9)$$

Under the assumption that the forces are small, the f_k^0 can be taken as homogeneous in this expression. Equation (8) does not uniquely define the set $\{\xi_i\}$. Onsager [33,34] argued that the optimal choice of $\{\xi_i\}$ is the one that maximizes the rate of entropy production from scattering. Appendix A, modeled after Ref. [35], gives an explicit derivation in the present context. The three terms in Eq. (8) represent the rates of entropy change from the external field, temperature gradient, and scattering: $\dot{S}_{\text{scatter}} = -\dot{S}_{\text{field}} - \dot{S}_{\text{inhom}}$. Following the optimization procedure in Appendix B, we find

$$\xi_i = \sum_j (P^{-1})_{ij} \left[\frac{j_\alpha^{(j)} E_\alpha}{T} + u_\alpha^{(j)} \nabla_\alpha \left(\frac{1}{T} \right) \right]. \quad (10)$$

We define the thermoelectric matrix, following Ref. [31], as

$$\begin{pmatrix} J \\ U \end{pmatrix} = L \begin{pmatrix} E \\ \nabla T \end{pmatrix}, \quad (11)$$

where $J_\alpha = \sum_i \xi_i j_\alpha^{(i)}$ and $U_\alpha = \sum_i \xi_i u_\alpha^{(i)}$ are the total number and heat currents. Inserting Eq. (10) into these definitions yields

$$L = \begin{pmatrix} \sum_{ij} j_\alpha^{(i)} (P^{-1})_{ij} j_\beta^{(j)} & -\frac{1}{T} \sum_{ij} j_\alpha^{(i)} (P^{-1})_{ij} u_\beta^{(j)} \\ \sum_{ij} u_\alpha^{(i)} (P^{-1})_{ij} j_\beta^{(j)} & -\frac{1}{T} \sum_{ij} u_\alpha^{(i)} (P^{-1})_{ij} u_\beta^{(j)} \end{pmatrix}. \quad (12)$$

One can determine a variety of transport coefficients in terms of the components of the thermoelectric matrix. In this paper, we report the DC charge and thermal resistivities ($\rho = 1/\sigma$ and $1/\kappa$, respectively), the Seebeck coefficient (α), and the

Lorenz number ($L_0 = \frac{\kappa}{T\sigma}$):

$$\begin{aligned} \rho &= \frac{1}{L_{11}}, & 1/\kappa &= -\frac{L_{11}}{\det(L)}, \\ \alpha &= -\frac{L_{12}}{L_{11}}, & L_0 &= -\frac{1}{T} \frac{\det(L)}{L_{11}^2}. \end{aligned} \quad (13)$$

One can readily verify that the entropy-maximizing condition produces an upper bound on ρ and the *bare* thermal resistivity, $1/\bar{\kappa} = 1/L_{22}$. This bare resistivity corresponds to the thermal response for $E = 0$, as opposed to the more physical condition $J = 0$. The other coefficients, α , κ , and L_0 , do not necessarily satisfy a variational bound.

III. RESULTS

We use two trial functions in the variational calculation: $\phi_k^{(1)} = (\nabla_k \epsilon_k)_x$ and $\phi_k^{(2)} = (\epsilon_k - \mu)(\nabla_k \epsilon_k)_x$. These are natural deviations from equilibrium to generate charge ($\phi^{(1)}$) and heat ($\phi^{(2)}$) currents. In Appendix F we estimate that the resulting low-temperature resistivities are accurate to within 30%. We expect similar accuracy at high temperature.

We divide our results between electrical and thermal properties in Secs. III A and III B, respectively.

A. Resistivity and scattering rate

Figure 1 shows the resistivity of the 2D Fermi-Hubbard model due to quasiparticle-quasiparticle scattering, calculated

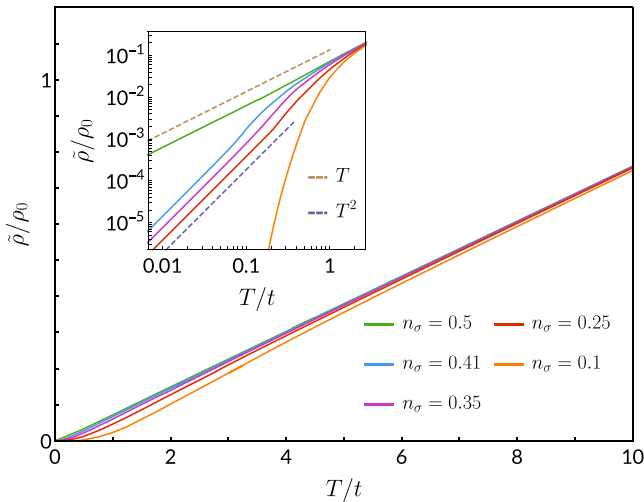


FIG. 1. Rescaled resistivity $\tilde{\rho} = (t/U)^2 \rho$ versus temperature, scaled by $\rho_0 = e^2/\hbar$. Data are shown for a variety of densities: $n_\sigma = 0.5$ (green), 0.41 (blue), 0.35 (purple), 0.25 (red), and 0.1 (orange). The resistivity is a monotonic increasing function of temperature for all densities with a T -linear high-temperature asymptote $\tilde{\rho}_\infty/\rho_0 \approx 0.076 T/t$. This asymptote is approached most quickly for densities near half filling. Inset: Zoom in to low temperatures on a log-log scale, showing the crossover to T^2 behavior. At $n_\sigma \leq 0.185$ the Fermi surface is sufficiently small that no umklapp processes are possible at zero temperature, so the resistivity decays exponentially. At $n_\sigma = 0.5$, perfect nesting leads to asymptotic T -linear resistivity down to zero temperature. Power-law guides to the eye are given by the dashed lines.

by numerically performing the integrals from Sec. II B. In our weak-coupling picture, the only U -dependence comes from the fact that the scattering rate (and hence the resistivity) is proportional to $(U/t)^2$. We find that the resistivity is a monotonic increasing function of temperature that vanishes at $T = 0$. These are the hallmarks of metallic behavior. As will be explained in Sec. III A 1, the high-temperature asymptotic behavior is linear in temperature and independent of the particle density. Next-leading-order high-temperature corrections are of order $1/T$ and are minimized at half filling. The high-temperature T -linear behavior persists to surprisingly low temperature, and it would require very high-precision experiments to identify the deviations for $T \gtrsim t$. The deviations from linear are particularly small at half filling, though they are nonzero.

As seen in the inset of Fig. 1, at low temperature there are three different behaviors, depending on the filling. For $0 < |\mu_F| < 2t$ we find $\rho \propto T^2$, while for $\mu_F = 0$ we instead find $\rho \propto T$. In Sec. III A 2 we explain this difference in terms of band structure. For $|\mu_F| > 2t$, low-temperature umklapp scattering is forbidden and the resistivity falls off exponentially.

We define a scattering lifetime using the Einstein relation, $\sigma = D\chi_c$, and the definition of the diffusion constant in a quasiparticle system, $D = \frac{1}{d}\langle v^2 \rangle \tau$ (d is the number of spatial dimensions). It is straightforward to compute $\langle v^2 \rangle$, the average squared quasiparticle velocity, and χ_c , the charge compressibility, for the noninteracting gas. The resulting scattering

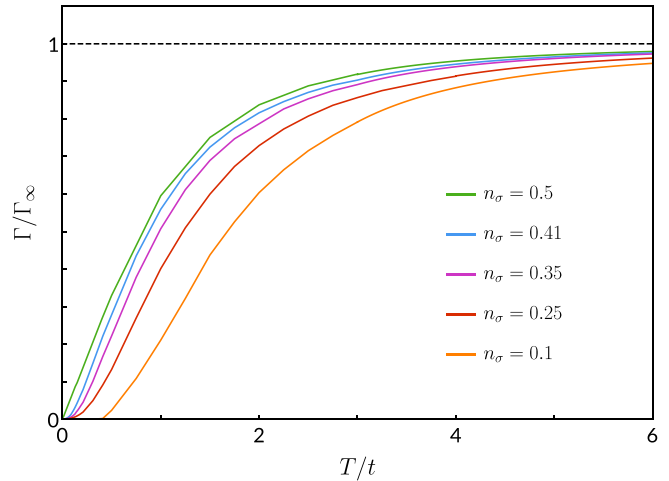


FIG. 2. Scattering rate Γ versus temperature in units of the high-temperature asymptote $\Gamma_\infty \approx 0.609 n_\sigma(1 - n_\sigma)U^2/\hbar t$. At low temperatures, $\Gamma \propto T^2$ for $0 < |\mu_F| < 2t$; the scattering rate vanishes as $\sim T$ at half filling and exponentially for $|\mu_F| > 2t$.

rate $\Gamma = 1/\tau$ is plotted in Fig. 2. In the limit of infinite temperature, the scattering rate saturates. At low temperature we again find three regimes: $\Gamma \propto T^2$, T , and $e^{-\Delta_U/T}$ for $0 < |\mu_F| < 2t$, $\mu_F = 0$, and $|\mu_F| > 2t$, respectively. Here $\Delta_U = 2(|\mu_F| - 2t)$ is the umklapp gap [36].

1. High temperature

Cold atom experiments measuring transport in the 2D Fermi-Hubbard model have thus far been limited to moderate-to-high temperatures, $T/t \gtrsim 1$ [22,37]. In this section we model this regime.

At high temperature we can expand the Fermi functions as $f_k^0 = n_\sigma - n_\sigma(1 - n_\sigma)\beta\epsilon_k$. It is then straightforward to write a high-temperature series expansion for the integrals in Eqs. (7) and (9). We find $\tilde{\rho}_\infty(T) = 0.076(T/t)\rho_0$, where $\rho_0 = e^2/\hbar$. Similarly $\Gamma_\infty = 0.609 n_\sigma(1 - n_\sigma)U^2/\hbar t$. A useful way to interpret these asymptotic results is in terms of a diverging effective mass within a Drude picture, where $\sigma = \frac{ne^2\tau}{m^*}$ with $\tau = 1/\Gamma$. There are positive and negative contributions to the inverse effective mass from the bottom and top of the band. These cancel at high temperatures, resulting in a divergent resistivity despite the fact that the scattering rate saturates. More precisely, in a relaxation time approximation

$$\left(\frac{n}{m^*}\right)_{\text{eff}} = \int \frac{d^2k}{2\pi^2} f_k(\nabla_k^2 \epsilon_k), \quad (14)$$

and for large T this integral vanishes as $1/T$.

We further interpret the scattering rate as $\Gamma = a^{-2}n_\sigma(1 - n_\sigma)\sigma_{\text{eff}}\bar{v}$, where n_σ is the dimensionless filling fraction and a is the lattice constant. Since the occupations f_k approach a constant as $T \rightarrow \infty$, the average velocity approaches $\bar{v} = \sqrt{\langle v^2 \rangle} \rightarrow 2at/\hbar$. This implies that the effective cross-section is $\sigma_{\text{eff}} = 0.3a(U/t)^2$. Up to the numerical prefactor, this last result can be derived from dimensional analysis and the Born approximation expression $\sigma_{\text{eff}} \propto U^2$.

While this calculation is only justified for perturbatively small U/t , it leads to arbitrarily large resistivity at sufficiently high temperature. This high-temperature divergence is well documented for single-band models [38–40], and we emphasize that this should not be interpreted as a violation of the MIR limit: the scattering rate and mean free path remain bounded.

2. Low temperature

Low-temperature quantities depend only on properties of the Fermi surface, and are derived by performing a Sommerfeld expansion [1]. Applying this expansion to Eq. (9) gives a leading-order T^2 behavior of the resistivity for generic filling (Appendix C) and T -linear behavior at half filling (Appendix D). The key features of this argument are described below, as well as a more qualitative argument. Only momentum nonconserving umklapp processes contribute to the resistivity at low temperature. When $|\mu_F| > 2t$, these processes are geometrically disallowed and the resistivity is exponentially small in $\Delta_U/k_B T$.

To reach a qualitative understanding of this behavior, we consider the rate at which a particle of momentum k_1 undergoes scattering. In particular, we consider processes $(k_1, k_2) \rightarrow (k_3, k_4)$, with energies $\epsilon_1, \epsilon_2, \epsilon_3, \epsilon_4$, with $|\epsilon_j - \mu_F| < k_B T$. At low temperature, the number of allowed choices of k_2 scale with T . Having fixed k_1 and k_2 , energy and momentum conservation constrains three of the four degrees of freedom of k_3 and k_4 . One therefore expects that the number of allowed final states should scale as T . Consequently, the scattering rate (and resistivity) scale as T^2 . One factor of T is associated with the freedom to choose k_2 and the other factor corresponds to redistributing energy between k_3 and k_4 .

At half filling the counting is slightly different. Up to logarithmic corrections from the divergent density of states, the number of allowed values of k_2 again scales as T . Energy and momentum conservation again restrict all but one degree of freedom of k_3 and k_4 . At half filling, however, the phase space for scattering is dominated by nested scattering events that are automatically within $k_B T$ of the Fermi surface. Thus the number of final states is independent of temperature and the scattering rate scales as T .

In Appendix D we put this argument on stronger mathematical foundations. We express the resistivity as an integral over the energy of pairs of scattering particles, and expand the Fermi functions to arrive at

$$\rho \propto \beta \int_{-8t}^{8t} dE \frac{(E/2 - \mu_F)^2}{\sinh^2[\beta(E/2 - \mu_F)]} f_T(E). \quad (15)$$

Up to numerical factors, $T^2 f_T(E)$ is the joint density of states for scattering, restricting the particle energies to be within $k_B T$ of $E/2$. It is well approximated by

$$f_T(E) = \begin{cases} \frac{1}{16\pi^4} \sqrt{\left(\frac{4t}{E}\right)^2 - 1}, & |E| > cT, \\ \frac{1}{16\pi^4} \sqrt{\left(\frac{4t}{cT}\right)^2 - 1}, & |E| \leq cT, \end{cases} \quad (16)$$

where c is a numerical constant. As long as $|\mu_F| \neq 0$, we can take the limit

$$\lim_{T \rightarrow 0} f_T(E) \equiv f(E) = \frac{1}{16\pi^4} \sqrt{(4t/E)^2 - 1}. \quad (17)$$

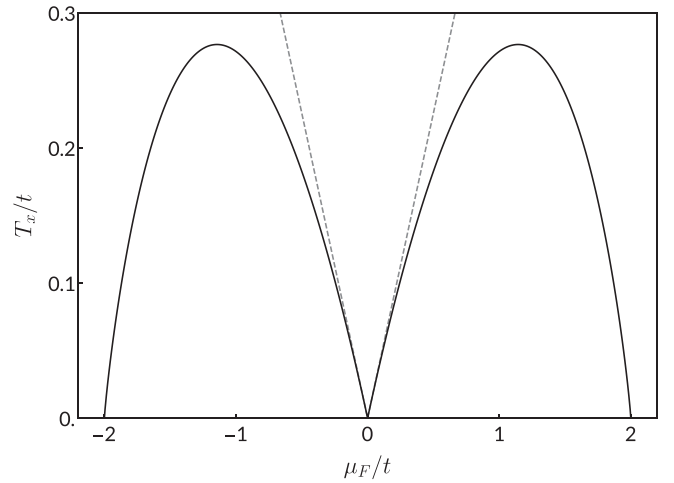


FIG. 3. Crossover temperature T_x , where the dominant T^2 term in the Sommerfeld expansion of the resistivity is equal to the exponentially suppressed subleading correction (black). Near half filling we see that the crossover temperature vanishes as $T_x \propto |\mu_F|$ (grey dashed line). Umklapp scattering is geometrically forbidden for small Fermi surfaces, which causes T_x to vanish as $|\mu_F| \rightarrow 2t$.

The first term in the integrand of Eq. (15) becomes a delta-function as $T \rightarrow 0$, and we recover the expected T^2 resistivity. At $\mu_F = 0$, however, $f_T(E) \propto 1/T$ and the resistivity is T -linear. For $|\mu_F| > 2t$ the resistivity vanishes as there are no allowed umklapp processes.

At generic filling, the strong $E = 0$ peak in $f_T(E)$ gives a subleading contribution to the resistivity which scales as $T e^{-2|\mu_F|/T}$. Thus one has a crossover between a low-temperature T^2 regime and a higher-temperature linear- T behavior. Figure 3 illustrates this crossover by finding the temperature, T_x , where this subleading term is equal to the dominant T^2 contribution. This crossover is also evident in the full numerical results in Fig. 1.

The crossover temperature vanishes as $|\mu_F| \rightarrow 2t$ due to the geometric exclusion of umklapp processes. Near half filling, T_x vanishes as $\sim |\mu|$ and it is natural to interpret the crossover in terms of the thermal occupation of the nested $E = 0$ states. At half filling, the crossover temperature vanishes. It is noteworthy that T_x is never larger than $0.3t$, which is an order of magnitude below the bandwidth.

B. Thermoelectric properties

Figure 4 shows the thermal resistivity $1/\kappa$ and the Lorenz number $L_0 = \kappa/T\sigma$, calculated using the techniques described in Sec. II. The thermal resistivity, plotted in units of $1/\kappa_0 = 1/\hbar t$, diverges as T^2 at high temperatures with a coefficient that is independent of the density: $\tilde{\kappa}_0/\tilde{\kappa}_\infty \approx 0.018 (T/t)^2$. Next-leading-order corrections give a small density-dependent vertical offset that vanishes at half filling. This high-temperature behavior can be modeled by the same techniques as in Sec. III A 1.

At low temperatures we find that $1/\kappa$ vanishes linearly in temperature for $0 < |\mu_F| < 2t$. At half filling the thermal resistivity approaches a constant ($1/\kappa \rightarrow 0.019/\kappa_0$) due to the same nesting argument as found in Sec. III A 2. For small

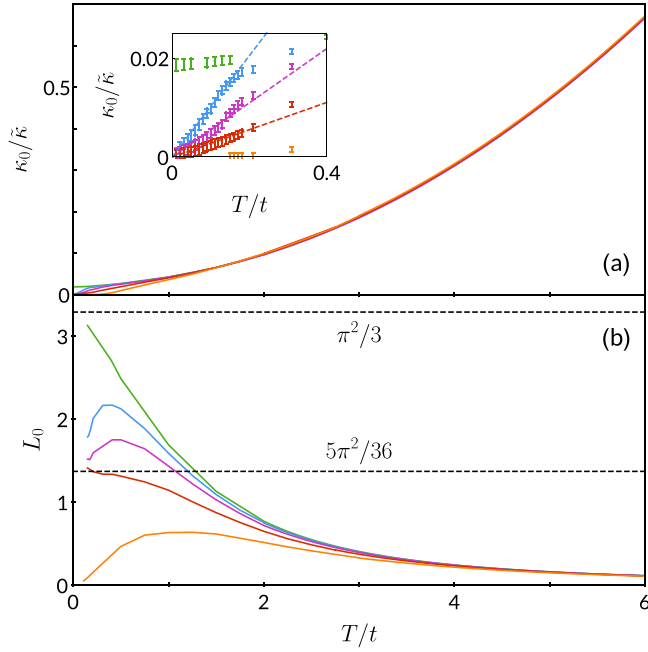


FIG. 4. (a) Scaled thermal resistivity $1/\bar{\kappa} = (t/U)^2(1/\kappa)$, in units of $1/\kappa_0 = 1/\hbar t$, as a function of temperature for a variety of fillings. See Fig. 1 for key. The thermal resistivity diverges as T^2 at high temperatures with a small vertical offset at finite doping. Inset: The thermal resistivity at low temperatures (dots) with error bars from estimated numerical uncertainty. Dotted lines give low-temperature expansion for $0 < |\mu_F| < 2t$; $1/\kappa$ vanishes exponentially for small Fermi surfaces ($|\mu_F| > 2t$). At half filling, the thermal resistivity approaches a constant value of $1/\bar{\kappa} \rightarrow 0.019/\kappa_0$. (b) Lorenz number $L_0 = \kappa/T\sigma$, versus temperature. The Lorenz number vanishes as $1/T^2$ at high temperatures. A Wiedemann-Franz law is satisfied at zero temperature for $0 < |\mu_F| < 2t$ with a Lorenz number of $5\pi^2/36$ and at half filling with a Lorenz number that appears to approach $\pi^2/3$ (labeled dashed lines); for $|\mu_F| > 2t$, the Lorenz number vanishes at low temperatures.

Fermi surfaces ($|\mu_F| > 2t$), umklapp processes are gapped out and $1/\kappa$ vanishes exponentially.

Comparing the temperature dependence of the thermal resistivity κ and the conductivity σ , we see that the Lorenz number $L_0 = \kappa/T\sigma$ approaches a constant at low temperature. This behavior is familiar from conventional materials, where elastic impurity scattering leads to $L_0^{\text{elastic}} = \pi^2/3$ at low temperatures. This Wiedemann-Franz relation is an indication that the same mechanism governs thermal and charge diffusion. It is often used as a means to judge the relative elasticity of resistive scattering events [41].

Through an expansion of the P_{ij} scattering integrals at low temperature, we find that for $0 < |\mu_F| < 2t$ the low-temperature Lorenz number is $L_0 = 5\pi^2/36$. This is somewhat smaller than the value coming from elastic impurity scattering. Figure 4 confirms this result. At half filling the Lorenz number appears to approach a different value $\pi^2/3$. This is indicative of a qualitative change in the scattering processes. For $|\mu_F| > 2t$ the Lorenz number vanishes at low temperature. At high temperatures, the Lorenz number vanishes as $1/T^2$: $\kappa \propto T^{-2}$, $\sigma \propto T^{-1}$.

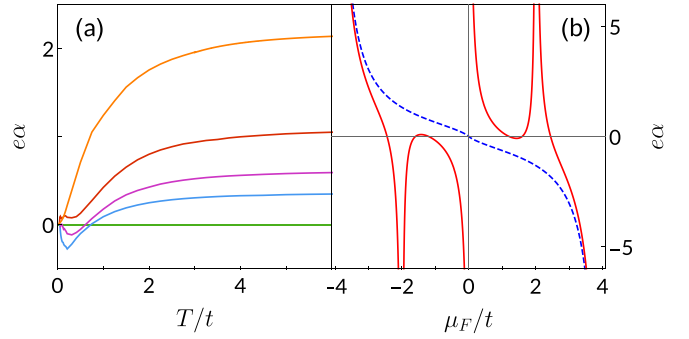


FIG. 5. (a) Seebeck coefficient α versus temperature T . At infinite temperatures, the Seebeck coefficient approaches the high-temperature free Fermi gas value $e\alpha_\infty = -\ln[(1 - n_\sigma)/n_\sigma]$. At low temperatures the Seebeck coefficient vanishes linearly with temperature. The Seebeck coefficient is particle-hole antisymmetric and is therefore strictly zero at half filling. (b) Slope of the leading-order low-temperature behavior of the Seebeck coefficient versus chemical potential (red) as well as the slope of the free Fermi gas Seebeck coefficient at zero temperature (blue). Introducing scattering causes the slope to diverge at half filling and at $|\mu_F| = 2t$. Exponentially suppressed umklapp scattering causes the deviation between the curves for $|\mu| > 2t$.

The Seebeck coefficient, or thermopower, α , characterizes the voltage induced by a thermal gradient. It is more complicated to understand than either the electrical and thermal resistivities. For example, it can have quite rich density dependence [42]. Figure 5(a) shows the temperature dependence of α . At high temperature it approaches the infinite-temperature noninteracting value, $e\alpha_\infty = -\log[(1 - n_\sigma)/n_\sigma]$, which is derived in Appendix E. This form is consistent with the Heikes formula [43,44]. At low temperatures the thermopower vanishes linearly in T for all fillings.

In Eq. (13) we argue that $\alpha = -L_{12}/L_{11}$ where L_{ij} involves a moment of the collision integral. Within the Born approximation, both L_{12} and L_{11} scale as U^{-2} , and hence α is independent of the interaction strength. Despite its independence from U , the α in Eq. (13) differs from that of the noninteracting Fermi gas, indicating that the $U \rightarrow 0$ limit is singular. Behavior in this regime is often understood in terms of the Mott formula [32]

$$e\alpha_{\text{Mott}} = T \frac{\pi^2}{3} \frac{d}{d\mu_F} \ln[\rho(\mu_F) \langle \tau(\epsilon, k) \nabla_k \epsilon_k \rangle_{\mu_F}]. \quad (18)$$

The density of states is given by $\rho(x)$ and $\langle \dots \rangle_{\mu_F}$ denotes momentum averaging over the Fermi surface. The low-temperature slope of the Seebeck coefficient in Fig. 5(b) diverges at half filling and at $|\mu_F| = 2t$ due to divergences in the log-derivative of the scattering lifetime at those points. It should be noted, however, that the radius of convergence of the low-temperature expansion vanishes at both of those points: beyond $T \approx t$, the effects of these low-temperature divergences are minimal. Umklapp scattering is exponentially suppressed when $|\mu_F| > 2t$, but nonetheless α vanishes linearly in T with a coefficient that differs from that of the ideal gas.

IV. DISCUSSION

A. High-temperature resistivity beyond weak coupling

An important conclusion of our work is that high-temperature T -linear resistivity is a feature of weakly coupled systems with a bounded spectrum. Such behavior is also seen at strong coupling [13,16,38–40]. The arguments, as presented in some of those papers, are generic, and we summarize them here.

We begin by considering the fluctuation-dissipation theorem [45]

$$\text{Re } \sigma(\omega) = \frac{1 - e^{-\beta\omega}}{2\omega} \int_{-\infty}^{\infty} dt e^{i\omega t} \Lambda(t), \quad (19)$$

which expresses the real part of the optical conductivity in terms of the current-current correlation function

$$\Lambda(t) = \text{Tr}[e^{-\beta\mathcal{H}} J(t) J(0)]. \quad (20)$$

Here J is the current operator and $J(t) = e^{i\mathcal{H}t} J e^{-i\mathcal{H}t}$. For a system with a bounded spectrum, such as the Fermi-Hubbard model, one can consider the limit where the temperature is large compared to all internal energy scales. We are then able to expand the thermal density matrix $e^{-\beta\mathcal{H}}$ in powers of β . The leading-order contribution to the conductivity is given by

$$\sigma(\omega) = \frac{\beta}{2} \int_{-\infty}^{\infty} dt e^{i\omega t} \text{Tr}[J(t) J(0)] + \dots \quad (21)$$

Assuming the integral is finite, one immediately sees that the resistivity $\rho = 1/\sigma(0)$ diverges linearly with temperature. This divergence is associated with *static* properties of the system (e.g., charge compressibility) rather than dynamical quantities (e.g., diffusion constant or scattering rate). Our weak coupling argument can be viewed as a special case of this general argument, where we are able to specifically attribute the divergence to the effective mass, $(n/m^*)_{\text{eff}}$.

By contrast, a resistivity that is linear-in-temperature at intermediate (relative to the energy spectrum of the system) or at asymptotically low temperatures is not generic and calls for a specific explanation [39] (cf. Sec. III A 2).

B. Experimental implications

While our results have general implications, they are most directly applied to cold atom experiments. To date there have been three experiments that measure the conductivity of the Fermi-Hubbard model. The first two experiments, by the Thywissen [46] and DeMarco [37] groups, explored three-dimensional (3D) Fermi-Hubbard transport. The Thywissen group applied a time-varying force to a harmonically trapped lattice gas and measuring the center-of-mass response [46]. They extracted $\sigma(\omega) = \langle j(\omega) \rangle / F(\omega)$, yielding a low-frequency conductivity and a transport scattering rate. The DeMarco group instead used a Raman pulse to generate spin currents in a 3D Fermi-Hubbard system [37]. From the subsequent decay of these currents they were able to extract a transport lifetime and define a resistivity. These two experiments are complementary in that one worked in the frequency domain and the other in the temporal domain.

The third cold atom experiment, by the Bakr group [22], involved a 2D lattice. They used an additional superlattice

potential to create a charge-density wave. After turning off the superlattice, they imaged the decay of the density wave. By repeating the experiment with different wave vectors, they extracted a diffusion constant and scattering rate. They also measured the charge compressibility, χ_c , and used the Nernst-Einstein equation to infer the conductivity $\sigma_{DC} = D\chi_c$. This experiment serves as the primary point of comparison for our calculations.

The top-line result of the Bakr experiment is that they see a T -linear resistivity, which bears a resemblance to the phenomenology of “strange-metallic” behavior in correlated metals [4–9]. This behavior persisted down to temperatures $T/t \lesssim 1$ despite nontrivial temperature dependence in the diffusion constant and compressibility. They also determine that the scattering rate saturates at high temperatures and exhibits a sharp downturn below $T/t \sim 4$. While our weak-coupling calculation does not quantitatively reproduce their results (as they have $U/t \approx 8$), we demonstrated that all qualitative features are present in the weak-coupling model. On the basis of these observations, we hypothesize that our results are continuously connected to their experiments.

The clearest test of this hypothesis would be to repeat the Bakr study with weaker interactions. This regime could be achieved by tuning the lattice depth, transverse confinement, or atomic scattering length (via a Feshbach resonance). One technical challenge with the weakly interacting limit is that, to avoid boundary effects, the atomic cloud must be large compared to the mean free path. For current experiments, with sizes of order 30 lattice spacings, this restricts $U \gtrsim 0.6t$ at $T/t = 0.5$.

An important aspect of our study is the crossover between the low-temperature T^2 and high-temperature T^1 resistivity. This crossover occurs at temperatures well below those studied in Ref. [22]. In addition to the challenges of achieving these temperatures, reliable low-temperature thermometry requires novel approaches [47]. The crossover temperature is greatest near fillings of $n_\sigma = 0.185$ and 0.815 , where the umklapp gap opens up.

Nesting plays an important role in our weakly interacting transport calculation. This physics can be explored by adding lattice anisotropy or a superlattice, both of which shift the filling at which nesting occurs. One can also study other lattices which do not display nesting [48–50].

The density dependence of the resistivity is at least as interesting as the temperature dependence. In particular, the most dramatic manifestation of strong-coupling physics is that at half filling the Fermi Hubbard model describes an interaction-driven insulator: when $T \lesssim U/10$, the resistivity rises as the temperature is reduced [28,29]. When U is large compared to t , one expects that proximity to this Mott physics will lead to density dependence of the resistivity which significantly differs from our weak-coupling results, even at intermediate temperatures [13].

In addition to calculating the electrical resistivity, we construct the full thermoelectric matrix, which also describes heat transport and thermoelectric effects. Measuring thermal transport in cold atoms is quite challenging, but there has been at least one successful experiment [51,52]. There the authors used a gate beam to separate two cold atom “reservoirs” with a quasi-2D channel. One reservoir is excited, and the

temperature of the both reservoirs is monitored. The thermal conductivity of the channel can then be deduced. One could imagine adding a lattice to this setup to measure the thermal conductivity of the Fermi Hubbard model. There may further be approaches based on tilted lattices which give access to the full thermoelectric matrix [53].

A more conventional approach to thermoelectric measurements of the Hubbard model might be achieved in transition metal dichalcogenide (TMD) heterobilayers, which realize 2D Fermi-Hubbard physics on a Moiré lattice [54]. Such a scheme would be advantageous insofar as conventional methods for thermoelectric transport could be used. One might tune the effective interaction strength by changing the distance between the gates and the sample: when the gates are closer, they more effectively screen the long-range Coulomb interaction. In general, however, the downside of TMDs compared to cold atoms is in the relative difficulty of tuning the interaction strength as well as the presence of a long-range interaction that complicates the theoretical analysis. Additionally, lattice defects and phonons may contribute to the resistivity.

C. Limits of validity

Our results are well controlled, and should be accurate for small U/t . Quantifying the exact range of validity, however, is challenging. For typical fillings, one would naively assume that the results are quantitative for $U \lesssim 0.1t$ and qualitatively accurate for $U \lesssim t$, but this would need to be verified by calculating the next-order terms. One could also potentially explore the range of validity by extending strong coupling calculations [13,16,18] to smaller U/t .

The precise range of validity will depend on the temperature and density of the system: at sufficiently low temperatures the half-filled Fermi-Hubbard model displays a nesting-driven instability [28,29] towards a Mott insulating state. This occurs at *any* $U/t > 0$, but the instability temperature falls with U/t . Conversely, the range of qualitative validity is likely considerably better in the dilute limit, where there are no nesting instabilities and the exact collision integral can be written in terms of the two-body T -matrix [55]. In this limit, one would expect the factor of $(U/t)^2$ to be renormalized, but the temperature dependence should not change dramatically.

In addition to assuming that $U \ll t$, we make use of a variational ansatz for the phase-space distribution function. In Appendix F we systematically explore the dependence of the resistivity on the trial functions. We find that at low temperature a more sophisticated ansatz rescales the resistivity, but does not change the temperature or density dependence.

V. CONCLUSION AND OUTLOOK

Experimental studies of cold atom transport in optical lattices are still in their relative infancy. The primary experimental papers cited here have all been published in the last three years, and their full impact has yet to be felt. Our paper approaches the transport problem from the weak-coupling side, in which calculations are tractable and the physical principles are readily extracted.

The key conclusion of our study is that even weak coupling models can host a variety of “unconventional”

transport properties. As has been well established in prior work [13,16,18,38–40], the high-temperature resistivity diverges in a single-band model. This divergence is not associated with a short mean-free path, but rather with a diverging effective mass. For all coupling strengths the transport coefficients are simple power laws $\rho \sim T$, $1/\kappa \sim T^2$, $\alpha \sim T^0$. The prefactors have nontrivial dependence U and n_σ . Mapping out this dependence on interactions and density is a prime target for future experiments.

At weak coupling, these high-temperature results persist to temperatures on the order of $T \approx t$ (or lower near half filling). While these are high temperatures in the context of condensed matter systems, it bears re-emphasizing that cold atom experiments have yet to probe transport at temperatures considerably colder than this.

At moderate temperatures, $1 < T/t < 4$, we find that the regime of near- T -linearity in the electrical resistivity is accompanied by a nontrivial order-of-magnitude decrease of the scattering rate. In our calculation, the featurelessness of the resistivity in this range of temperatures arises from an interplay between the quasiparticle scattering rate and the effective mass (or, equivalently, between the diffusion constant and the charge compressibility) that is entirely explicable in terms of band theory. We emphasize this point to draw a comparison to a similar phenomenon observed in the Bakr experiment [22], which probed the strongly interacting limit.

At low temperature, we use a Sommerfeld expansion to recover the expected Fermi-liquid result $\rho \propto T^2$ and similar expressions for the full thermoelectric matrix. The radius of convergence of this expansion is finite, and it vanishes at half filling, where $\rho \propto T$. This anomalous scaling arises from the continuum of umklapp scattering events enabled by the nested band structure. The nesting condition can also lead to various spin-density wave and charge-density wave instabilities which may preempt some of this behavior [23,28,29,48].

The prime motivator of the atomic Hubbard model experiments is trying to gain understanding of strongly correlated phenomena, including high-temperature superconductivity. Such insight will require much lower temperatures. The pseudogap regime in the cuprates occurs for $T \lesssim 0.1t$. Strange metal behavior is also apparent at those scales. The crossover between the weak-coupling physics explored in this paper and the strong-coupling physics seen in materials is likely to be quite rich and well suited for exploration using cold atom experiments.

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APPENDIX A: EQUATION OF MOTION FOR ENTROPY

For a given distribution function, f_k , the von Neumann entropy of the ensemble of fermions is

$$S = - \int \frac{d^2k}{(2\pi)^2} [f_k \ln f_k + (1 - f_k) \ln(1 - f_k)]. \quad (\text{A1})$$

Near equilibrium, the distribution function has the form

$$f_k = f_k^0 - \Phi_k \frac{\partial f_k^0}{\partial \epsilon_k}, \quad (\text{A2})$$

where Φ_k is small. We take the time derivative of Eq. (A1) and expand to leading order in Φ_k :

$$\begin{aligned} \dot{S} &= - \int \frac{d^2k}{(2\pi)^2} \ln \left(\frac{f_k}{1-f_k} \right) \dot{f}_k \\ &\approx - \int \frac{d^2k}{(2\pi)^2} [-\beta(\epsilon_k - \mu) + \beta\Phi_k] \dot{f}_k. \end{aligned} \quad (\text{A3})$$

We recognize Eq. (A3) as an equation of motion for the total entropy, $\dot{S} = \beta\dot{E} - \beta\mu\dot{N} + \dot{S}_{neq}$, and conclude

$$\dot{S}_{neq} = - \int \frac{d^2k}{(2\pi)^2} \beta\Phi_k \dot{f}_k. \quad (\text{A4})$$

Inserting \dot{f}_k from the linearized Boltzmann equation, Eq. (2), into Eq. (A4) leads to the conclusion that Eq. (8),

$$\sum_i \xi_i \left[\frac{j_\alpha^{(i)} E_\alpha}{T} + u_\alpha^{(i)} \nabla_\alpha \left(\frac{1}{T} \right) \right] = \frac{1}{T} \sum_{ij} \xi_i \xi_j P_{ij},$$

is equivalent to $\dot{S}_{neq} = 0$. The right-hand side is the rate of entropy production from scattering processes. This must equal the left-hand side, the rate at which this heat is carried away. In Appendix B, we show that the optimal distribution function f_k is obtained by maximizing the rate of entropy production.

APPENDIX B: VARIATIONAL PRINCIPLE

Following Ziman [31,35], here we derive a variational principle for transport coefficients. We begin by introducing compact notation, defining

$$X_k = -\nabla_r f_k^0 \cdot v_k + eE \cdot \nabla_k f_k^0 \quad (\text{B1})$$

as the left-hand side of the steady-state Boltzmann equation, expanded to linear order in the electric field and thermal gradients. We think of X_k as components of a vector and write X as the abstract vector. Similarly, Φ is the abstract vector with components Φ_k [see Eq. (A2)]. We define the positive definite linear operator P as

$$(P\Phi)_k = -I_k[\Phi], \quad (\text{B2})$$

where $I_k[\Phi]$ is the linearized collision integral defined in Eq. (6). The linearized Boltzmann equation then reads

$$X = P\Phi. \quad (\text{B3})$$

We introduce an inner product

$$\langle \Phi, \Psi \rangle = \int \frac{d^2k}{(2\pi)^2} \Phi(k) \Psi(k). \quad (\text{B4})$$

Taking the inner product of Eq. (B3) with Φ yields

$$\langle \Phi, X \rangle = \langle \Phi, P\Phi \rangle, \quad (\text{B5})$$

which can be recognized as the equation for entropy balance, Eq. (8).

Let Φ be the exact solution to Eq. (B3) and let Ψ be a variational ansatz which obeys Eq. (B5), i.e.,

$$\langle \Psi, X \rangle = \langle \Psi, P\Psi \rangle. \quad (\text{B6})$$

We will show that

$$\langle \Phi, P\Phi \rangle \geq \langle \Psi, P\Psi \rangle, \quad (\text{B7})$$

and hence the best variational solution is the one that maximizes $\langle \Psi, P\Psi \rangle$. As argued in Appendix A, this corresponds to maximizing the entropy produced in collisions.

The proof is straightforward. Since P is positive definite $\langle (\Psi - \Phi), P(\Psi - \Phi) \rangle \geq 0$. Expanding this out yields

$$\langle \Phi, P\Phi \rangle \geq -\langle \Psi, P\Psi \rangle + \langle \Psi, P\Phi \rangle + \langle \Phi, P\Psi \rangle. \quad (\text{B8})$$

Explicitly writing out the integral reveals $\langle \Phi, P\Psi \rangle = \langle \Psi, P\Phi \rangle$. We then use Eqs. (B3) and (B6) to find $\langle \Psi, P\Phi \rangle = \langle \Psi, X \rangle = \langle \Psi, P\Psi \rangle$. Substituting this into Eq. (B8) yields the desired result, Eq. (B7).

APPENDIX C: COLLISION INTEGRAL AT LOW TEMPERATURE

Here we discuss the Sommerfeld expansion of the collision integral at low temperatures. We will limit ourselves to $|\mu_F| \neq 0$, leaving the discussion of the half-filled case for Appendix D. We will use a one-component ansatz, with $\phi_k = (\nabla_k \epsilon)_x = 2t \sin k_x$.

Our starting point is Eq. (9). We rewrite the energy and momentum delta functions as

$$\begin{aligned} \delta(\epsilon_k + \epsilon_{k'} - \epsilon_{k''} - \epsilon_{k'''}) &= \int dE \delta(\epsilon_k + \epsilon_{k'} - E) \\ &\quad \times \delta(\epsilon_{k''} + \epsilon_{k'''} - E), \end{aligned} \quad (\text{C1})$$

$$\begin{aligned} &\sum_Q \delta^{(2)}(k + k' - k'' - k''' - Q) \\ &= \sum_Q \int d^2K \delta^{(2)}(k + k' - K) \delta^{(2)}[k'' + k''' - (K - Q)]. \end{aligned} \quad (\text{C2})$$

We now take the low-temperature limit of the product of Fermi functions, noting that both $f(\epsilon)f(E-\epsilon)$ and $[1-f(\epsilon)][1-f(E-\epsilon)] = e^{\beta(E-\mu_F)} f(\epsilon)f(E-\epsilon)$ are sharply peaked about $\epsilon = E/2$, and that

$$\int d\epsilon \frac{1}{e^{\beta(\epsilon-\mu_F)} + 1} \frac{1}{e^{\beta(E-\epsilon+\mu_F)} + 1} = \frac{E - 2\mu_F}{1 - e^{\beta(E-\mu_F)}}, \quad (\text{C3})$$

which leads to the approximation

$$\begin{aligned} &f_k^0 f_{k'}^0 (1 - f_{k''}^0) (1 - f_{k'''}^0) \\ &\approx \frac{(E/2 - \mu_F)^2}{\sinh^2[\beta(E/2 - \mu_F)]} \delta(\epsilon_k - E/2) \delta(\epsilon_{k''} - E/2). \end{aligned} \quad (\text{C4})$$

We substitute this leading behavior into Eq. (9), yielding a resistivity, $\rho = P/j^2$, of the form

$$\rho = \frac{\beta}{j^2} \int_{-8t}^{8t} \frac{(E/2 - \mu_F)^2}{\sinh^2 \beta(E/2 - \mu_F)} f(E) dE, \quad (\text{C5})$$

where $f(E)$ is an integral over the center-of-mass momenta of the colliding pairs that will be discussed below. The current at

zero temperature is simply $j(\mu_F) = 2(e/\hbar) \zeta(\mu_F/4t)$ where

$$\zeta(y) = \frac{4|y|}{\pi^2} [E(1 - y^{-2}) - \Pi(1 + y^{-1}, 1 - y^{-2}) - \Pi(1 - y^{-1}, 1 - y^{-2})] \quad (\text{C6})$$

and $E(k)$ and $\Pi(n, k)$ are complete elliptic integrals of the second and third kinds, respectively. If f is well behaved in Eq. (C5), one can replace

$$\frac{(E/2 - \mu_F)^2}{\sinh^2 \beta(E/2 - \mu_F)} \rightarrow \frac{\pi^2}{3} T^3 \delta(E/2 - \mu), \quad (\text{C7})$$

which yields

$$\rho = \frac{\pi^2}{3} T^2 f(2\mu_F) / [j(\mu_F)]^2. \quad (\text{C8})$$

The function $f(E)$ in Eq. (C5) involves an integral over the incoming momenta k, k' and the outgoing momenta k'' and k''' . Due to momentum conservation, we can write $f(E) = \int d^2K g(E, K)$, where K is the center-of-mass momentum, and g is an integral over the relative momenta. The only term

in Eq. (9) coupling the incoming and outgoing integrals is the factor $(\phi_k + \phi_{k'} - \phi_{k''} - \phi_{k'''})^2$. Expanding this quadratic allows us to express g as a sum of four terms, each of which are a product of incoming and outgoing terms,

$$g(E, K) = \sum_Q \frac{4}{(2\pi)^5} [F^{(2)}(E, K)F^{(0)}(E, K - Q) + F^{(2)}(E, K - Q)F^{(0)}(E, K) - 2F^{(1)}(E, K)F^{(1)}(E, K - Q)], \quad (\text{C9})$$

where

$$F^{(m)}(E, K) = 2 \sin \frac{K_x}{2} \int_{-\pi}^{\pi} d^2q \cos^m(q_x) \times \delta(\epsilon_{q+K/2} + \epsilon_{q-K/2} - E) \delta(\epsilon_{q+K/2} - \epsilon_{q-K/2}) \quad (\text{C10})$$

and $K/2 \pm q$ are the momenta of the two scattering particles. Changing coordinates to $u = \cos(K_x/2)$ and $v = \cos(K_y/2)$, this can be rearranged to find

$$f(E) = \frac{1}{4\pi^5} \int_{|E|/4}^1 \frac{dv}{\sqrt{1-v^2}} \int_0^{v-|E|/4} \frac{du}{\sqrt{1-u^2}} \frac{v^2 + u^2 - 2u^2v^2}{\sqrt{(u^2 - v^2)^2 [E^2/16 - (u+v)^2] [E^2/16 - (u-v)^2]}}. \quad (\text{C11})$$

We find empirically that this integral evaluates to

$$f(E) = \frac{1}{16\pi^4} \sqrt{(4t/E)^2 - 1}. \quad (\text{C12})$$

The physical consequences are discussed in Sec. III A 2.

APPENDIX D: PHASE-SPACE INTEGRALS AT HALF FILLING

As presented, the integral in Eq. (C5) is divergent due to the fact that $f(E) \propto E^{-1}$ for small E . This divergence is an artifact of the approximation in Eq. (C4) where the product of Fermi functions is replaced with infinitely sharp delta-functions. Here we show that at finite T the divergence is cutoff, and as $T \rightarrow 0$, $f(E=0) \propto \beta$.

Including the finite widths of the Fermi function steps, Eq. (C4) takes on the form

$$f_k^0 f_{k'}^0 (1 - f_{k''}^0) (1 - f_{k'''}^0) \approx \frac{(E/2 - \mu)^2}{\sinh^2[\beta(E/2 - \mu)]} \times \delta_\beta(\epsilon_k - E/2) \delta_\beta(\epsilon_{k''} - E/2), \quad (\text{D1})$$

where $\delta_\beta(x)$ has area 1 and a width that scales as $1/\beta$. The exact form is not important. Setting $E = 0$, the phase-space integrals that appear in Eq. (C9) become

$$F^{(m)} = 2 \sin \left(\frac{1}{2} K_x \right) \int_{-\pi}^{\pi} d^2k \cos^m(k_x) \delta(\epsilon_{k+K/2} + \epsilon_{k-K/2}) \times \delta_\beta(\epsilon_{k+K/2} - \epsilon_{k-K/2}). \quad (\text{D2})$$

Note, the energy conserving delta-function is not broadened. For $E = 0$, the function $F^{(1)}$ vanishes due to symmetry.

Along the diagonals ($K_x = \pm K_y$) the integrand is poorly behaved, and as $\beta \rightarrow \infty$ the integral is dominated by those regions. To calculate the contribution from one diagonal, we shift the center-of-mass variables $K_x = P + q$ and $K_y = P - q$, and consider the region where $|q| \ll P$. The contribution from the other diagonals is identical.

The functions $F^{(0)}$ and $F^{(2)}$ have the same scaling with β , so we only give the arguments for $F^{(0)}$. We use the energy conservation delta-function to perform the k_y integral, treating q as small,

$$F^{(0)}(K; \beta) \sim \int dk_x \frac{1}{|\sin(k_x)|} \delta_\beta \left(4q \cos(P/2) \sin(|k_x|) - 4q \frac{\sin^2(P/2) \cos^2(k_x)}{\cos(P/2) \sin(k_x)} \right). \quad (\text{D3})$$

There are now two small parameters in this problem ($1/\beta$ and q), so we must consider the asymptotic behavior of the integral for $\beta q \gg 1$ and $\beta q \ll 1$ independently. In the first case, the broadened delta function is only nonzero when k_x is within $\sim 1/|\beta q|$ of the points $P/2$ and $\pi - P/2$. The factor of $1/|\sin(k_x)|$ is well behaved in these regions, and we can replace it with $1/|\sin(P/2)|$. Treating δ_β as a box function, we see that the $\beta q \gg 1$ contribution to the integral scales as $F^> \sim \beta(1/\beta q)^2$. The contribution to $f(E=0)$ from this region is then

$$f^> \sim \beta^2 \int_{1/\beta} \frac{dq}{q^4} \sim \beta. \quad (\text{D4})$$

The $\beta q \ll 1$ contribution to the integral comes from the region where k_x is not within $|\beta q|$ of the points 0 and $\pm\pi$. The integrand diverges as $1/|k_x|$ near these points, so we need only

consider the behavior in their vicinity

$$F^< \sim \beta \int_{\beta q} \frac{dk_x}{|k_x|} \sim -\beta \ln(\beta q). \quad (\text{D5})$$

The contribution to f is has the same scaling

$$f^< \sim \int_0^{1/\beta} dq \beta^2 [\ln(\beta q)]^2 \sim \beta. \quad (\text{D6})$$

Thus we established that the divergence is cutoff, as described by Eq. (16).

APPENDIX E: SEEBECK COEFFICIENT OF NONINTERACTING GAS

While some transport coefficients, such as the electrical and thermal resistivities, are undefined in the absence of scattering, the free Fermi gas has a well-defined Seebeck coefficient. The steady-state, collisionless Boltzmann equation describes the behavior of the distribution function in response to electric fields and inhomogeneities: Eq. (2) with $\partial_t f_k = 0$ and $I_k[f] = 0$. As in Eq. (5), we take $T(r)$ and $\mu(r)$ to be slowly varying, writing $f_k = f_k^0(r)$. We absorb spatial derivatives of $\mu(r)$ into the definition of the field, and hence the relevant spatial derivatives of f_k are proportional to $\nabla_r T$. We then take the moment of the Boltzmann equation with respect to $\nabla_k \epsilon_k$ to arrive at a steady-state condition for the particle number current

$$\nabla_r T \int \frac{d^2 k}{(2\pi)^2} (\nabla_k \epsilon_k)^2 \frac{\partial f_k}{\partial T} + eE \int \frac{d^2 k}{(2\pi)^2} (\nabla_k \epsilon_k)^2 \frac{\partial f_k}{\partial \epsilon_k} = 0, \quad (\text{E1})$$

The Seebeck coefficient relates the electric field and thermal gradient $E = \alpha \nabla_r T$ under the condition of a vanishing number current. We therefore rearrange Eq. (E1) to find

$$e\alpha = \beta \frac{\int \frac{d^2 k}{(2\pi)^2} (\epsilon_k - \mu) (\nabla_k \epsilon_k)^2 f_k^0 (1 - f_k^0)}{\int \frac{d^2 k}{(2\pi)^2} (\nabla_k \epsilon_k)^2 f_k^0 (1 - f_k^0)}. \quad (\text{E2})$$

At high temperature, $T \rightarrow \infty$, the Seebeck coefficient approaches $e\alpha \rightarrow -\beta \mu = \log[n_\sigma / (1 - n_\sigma)]$. At low temperature, $T \rightarrow 0$, the Seebeck coefficient vanishes linearly with temperature.

APPENDIX F: ACCURACY OF TRIAL FUNCTIONS

Here we evaluate the accuracy of our variational trial wave function by systematically including higher moments. We consider the low-temperature limit, calculating ρ via

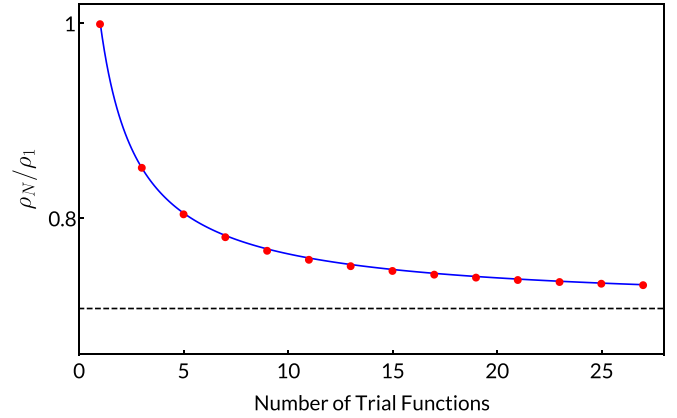


FIG. 6. Low-temperature resistivity ρ_N calculated using a variational ansatz using N trial functions of the form $\phi^{(i)} = (\epsilon_k - \mu)^{i-1} (\nabla_k \epsilon_k)_x$. At low temperature including more terms simply rescales the resistivity, and the ratio ρ_N / ρ_1 is independent of all microscopic parameters. Blue line: Best fit of the form $\rho_N / \rho_1 = 1 - A \sum_{i=1}^N i^{-\alpha}$, with $\alpha = 1.86$ and $A = 0.368$. Black dashed line: Asymptote of the fitting curve at $\rho_\infty / \rho_1 = 0.707$.

Eq. (13), including N trial functions of the form $\phi^{(i)} = (\epsilon_k - \mu)^{i-1} (\nabla_k \epsilon_k)_x$. At low temperatures, the scattering integrals P_{ij} defined in Eq. (9) can be expanded as shown in Appendix C. In particular, using the approximation in Eq. (C4) the low-temperature expression for P_{ij} is

$$P_{ij} = \beta \int_{-8t}^{8t} \frac{(E/2 - \mu_F)^{i+j}}{\sinh^2 \beta(E/2 - \mu_F)} f_T(E) dE, \quad (\text{F1})$$

where the function $f_T(E)$ is defined in Eq. (16). We then expand the integrand using Eq. (C7) to determine the leading-order low-temperature behavior of P_{ij} . The currents $j^{(i)}$ and $u^{(i)}$ [see Eq. (7)] are expanded in an analogous manner, and we determine the thermoelectric matrix using Eq. (12).

We define ρ_N as the resistivity calculated using all trial function $\phi^{(i)}$ with $i \leq N$. We find that including terms beyond $N = 1$ simply rescales the thermoelectric response functions: at low temperatures the ratios between different approximants ρ_N / ρ_1 are temperature and density independent.

Figure 6 shows how the resistivity changes as we add more terms to our ansatz. The calculation is variational, so the resistivity monotonically decreases as more terms are added. Extrapolating $N \rightarrow \infty$ gives a 30% reduction from the $N = 2$ result discussed in the main paper. More general ansätze are unlikely to significantly change this result. Similarly, it is reasonable to assume that this estimate of the error applies at all temperatures.

- [1] P. Coleman, *Introduction to Many-Body Physics* (Cambridge University Press, Cambridge, England, 2015).
- [2] N. F. Mott, *Philosophical Magazine: J. Theor. Exp. Appl. Phys.* **26**, 1015 (1972).
- [3] A. F. Ioffe and A. R. Regel, *Prog. Semicond.* **4**, 237 (1960).
- [4] N. E. Hussey, *J. Phys.: Condens. Matter* **20**, 123201 (2008).
- [5] S. A. Grigera, R. S. Perry, A. J. Schofield, M. Chiao, S. R. Julian, G. G. Lonzarich, S. I. Ikeda, Y. Maeno,

A. J. Millis, and A. P. Mackenzie, *Science* **294**, 329 (2001).

- [6] N. Doiron-Leyraud, P. Auban-Senzier, S. René de Cotret, C. Bourbonnais, D. Jérôme, K. Bechgaard, and L. Taillefer, *Phys. Rev. B* **80**, 214531 (2009).

- [7] H. v. Löhneysen, T. Pietrus, G. Portisch, H. G. Schlager, A. Schröder, M. Sieck, and T. Trappmann, *Phys. Rev. Lett.* **72**, 3262 (1994).

- [8] A. Legros, S. Benhabib, and W. E. A. Tabis, *Nat. Phys.* **15**, 142 (2019).
- [9] J. A. N. Bruin, H. Sakai, R. S. Perry, and A. P. Mackenzie, *Science* **339**, 804 (2013).
- [10] C. M. Varma, P. B. Littlewood, S. Schmitt-Rink, E. Abrahams, and A. E. Ruckenstein, *Phys. Rev. Lett.* **63**, 1996 (1989).
- [11] J. Vučičević, D. Tanasković, M. J. Rozenberg, and V. Dobrosavljević, *Phys. Rev. Lett.* **114**, 246402 (2015).
- [12] S. Hartnoll, A. Lucas, and S. Sachdev, *Holographic Quantum Matter* (MIT Press, Cambridge, MA, 2018).
- [13] E. Perepelitsky, A. Galatas, J. Mravlje, R. Žitko, E. Khatami, B. S. Shastry, and A. Georges, *Phys. Rev. B* **94**, 235115 (2016).
- [14] C. H. Mousatov, I. Esterlis, and S. A. Hartnoll, *Phys. Rev. Lett.* **122**, 186601 (2019).
- [15] J. Vučičević, J. Kokalj, R. Žitko, N. Wentzell, D. Tanasković, and J. Mravlje, *Phys. Rev. Lett.* **123**, 036601 (2019).
- [16] E. W. Huang, R. Sheppard, B. Moritz, and T. P. Devereaux, *Science* **366**, 987 (2019).
- [17] P. Cha, A. A. Patel, E. Gull, and E.-A. Kim, *Phys. Rev. Research* **2**, 033434 (2020).
- [18] X. Deng, J. Mravlje, R. Žitko, M. Ferrero, G. Kotliar, and A. Georges, *Phys. Rev. Lett.* **110**, 086401 (2013).
- [19] I. Bloch, J. Dalibard, and W. Zwerger, *Rev. Mod. Phys.* **80**, 885 (2008).
- [20] C. Chin, R. Grimm, P. Julienne, and E. Tiesinga, *Rev. Mod. Phys.* **82**, 1225 (2010).
- [21] R. E. Peierls, *Quantum Theory of Solids* (Oxford University Press, Oxford, 1955).
- [22] P. T. Brown, D. Mitra, E. Guardado-Sanchez, R. Nourafkan, A. Reymbaut, C.-D. Hébert, S. Bergeron, A.-M. S. Tremblay, J. Kokalj, D. A. Huse, P. Schauß, and W. S. Bakr, *Science* **363**, 379 (2019).
- [23] A. Virosztek and J. Ruvalds, *Phys. Rev. B* **42**, 4064 (1990).
- [24] S. Fujimoto, H. Kohno, and K. Yamada, *J. Phys. Soc. Jpn.* **60**, 2724 (1991).
- [25] P. Schlottmann, *J. Appl. Phys.* **97**, 10A917 (2005).
- [26] P. A. Lee and N. Read, *Phys. Rev. Lett.* **58**, 2691 (1987).
- [27] J. González and T. Stauber, *Phys. Rev. Lett.* **124**, 186801 (2020).
- [28] T. Schäfer, F. Geles, D. Rost, G. Rohringer, E. Arrigoni, K. Held, N. Blümer, M. Aichhorn, and A. Toschi, *Phys. Rev. B* **91**, 125109 (2015).
- [29] F. Šimković, J. P. F. LeBlanc, A. J. Kim, Y. Deng, N. V. Prokof'ev, B. V. Svistunov, and E. Kozik, *Phys. Rev. Lett.* **124**, 017003 (2020).
- [30] R. Franz and G. Wiedemann, *Ann. Phys. (Leipzig)* **165**, 497 (1853).
- [31] J. M. Ziman, *Electrons and Phonons: The Theory of Transport Phenomena in Solids* (Oxford University Press, Oxford, 1960).
- [32] N. Ashcroft and N. Mermin, *Solid State Physics* (Saunders College, Philadelphia, 1976).
- [33] L. Onsager, *Phys. Rev.* **37**, 405 (1931).
- [34] L. Onsager, *Phys. Rev.* **38**, 2265 (1931).
- [35] J. M. Ziman, *Can. J. Phys.* **34**, 1256 (1956).
- [36] A. Rosch, *Ann. Phys. (Leipzig)* **15**, 526 (2006).
- [37] W. Xu, W. McGehee, W. Morong, and B. DeMarco, *Nat. Commun.* **10**, 1588 (2019).
- [38] S. Mukerjee, V. Oganesyan, and D. Huse, *Phys. Rev. B* **73**, 035113 (2006).
- [39] A. A. Patel and H. J. Changlani, Many-body energy invariant for t -linear resistivity, [arXiv:2106.01381](https://arxiv.org/abs/2106.01381).
- [40] N. H. Lindner and A. Auerbach, *Phys. Rev. B* **81**, 054512 (2010).
- [41] A. Lavasani, D. Bulmash, and S. Das Sarma, *Phys. Rev. B* **99**, 085104 (2019).
- [42] A. Garg, B. S. Shastry, K. B. Dave, and P. Phillips, *New J. Phys.* **13**, 083032 (2011).
- [43] R. R. Heikes, R. W. Ure, S. J. Angello, and J. E. Bauerle, *Thermoelectricity Science and Engineering* (Interscience Publishers, 1961).
- [44] P. M. Chaikin and G. Beni, *Phys. Rev. B* **13**, 647 (1976).
- [45] R. Kubo, *J. Phys. Soc. Jpn.* **12**, 570 (1957).
- [46] R. Anderson, F. Wang, P. Xu, V. Venu, S. Trotzky, F. Chevy, and J. H. Thywissen, *Phys. Rev. Lett.* **122**, 153602 (2019).
- [47] T. Hartke, B. Oreg, N. Jia, and M. Zwierlein, *Phys. Rev. Lett.* **125**, 113601 (2020).
- [48] M. Qin, T. Schäfer, S. Andergassen, P. Corboz, and E. Gull, [arXiv:2104.00064](https://arxiv.org/abs/2104.00064).
- [49] A. Vranić, J. Vučičević, J. Kokalj, J. Skolimowski, R. Žitko, J. Mravlje, and D. Tanasković, *Phys. Rev. B* **102**, 115142 (2020).
- [50] J. F. Mendez-Valderrama and D. Chowdhury, *Phys. Rev. B* **103**, 195111 (2021).
- [51] J.-P. Brantut, C. Grenier, J. Meineke, D. Stadler, S. Krinner, C. Kollath, T. Esslinger, and A. Georges, *Science* **342**, 713 (2013).
- [52] S. Häusler, P. Fabritius, J. Mohan, M. Lebrat, L. Cormann, and T. Esslinger, *Phys. Rev. X* **11**, 021034 (2021).
- [53] E. Guardado-Sanchez, A. Morningstar, B. M. Spar, P. T. Brown, D. A. Huse, and W. S. Bakr, *Phys. Rev. X* **10**, 011042 (2020).
- [54] Y. Tang, L. Li, T. Li, Y. Xu, S. Liu, K. Barmak, K. Watanabe, T. Taniguchi, A. H. MacDonald, J. Shan, and K. F. Mak, *Nature (London)* **579**, 353 (2020).
- [55] R. G. Newton, *Scattering Theory of Waves and Particles* (Springer-Verlag, Berlin, 1982).